

TC7MH273FK

Octal D-Type Flip Flop with Clear

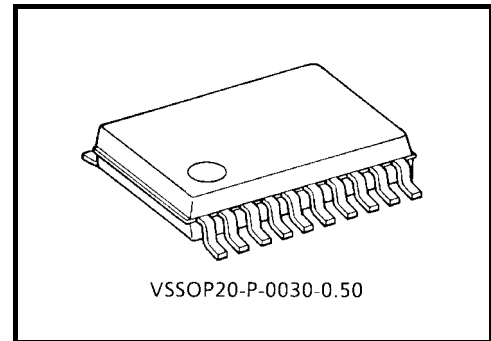
The TC7MH273FK is an advanced high speed CMOS octal D-type flip-flop fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

Information signals applied to D inputs are transferred to the Q outputs on the positive going edge of the clock pulse.

When the $\overline{\text{CLR}}$ input is held "L", the Q outputs are at a low logic level independent of the other inputs.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

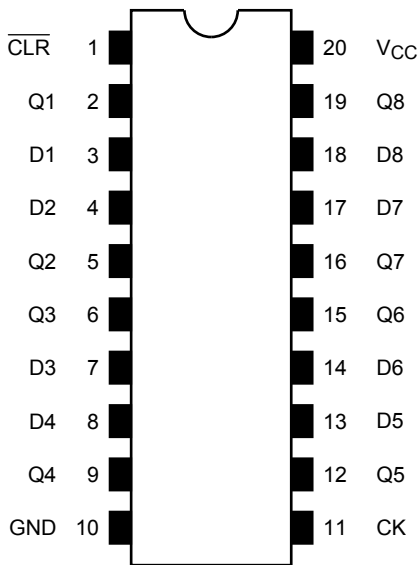


Weight: 0.03 g (typ.)

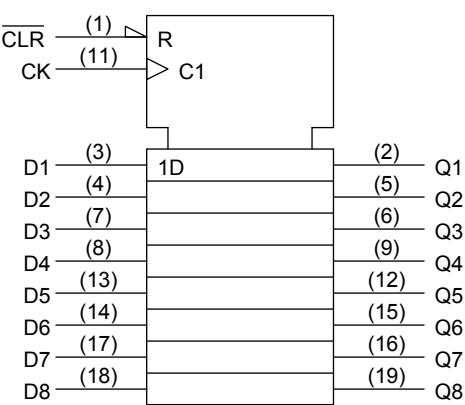
Features

- High speed: $f_{\text{max}} = 165 \text{ MHz (typ.) (VCC = 5 V)}$
- Low power dissipation: $I_{\text{CC}} = 4 \mu\text{A (max) (Ta = 25}^\circ\text{C)}$
- High noise immunity: $V_{\text{NIH}} = V_{\text{NIL}} = 28\% V_{\text{CC (min)}}$
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{\text{pLH}} \approx t_{\text{pHL}}$
- Wide operating voltage range: $V_{\text{CC (opr)}} = 2 \sim 5.5 \text{ V}$
- Low noise: $V_{\text{OLP}} = 0.8 \text{ V (max)}$
- Pin and function compatible with 74ALS273

Pin Assignment (top view)



IEC Logic Symbol

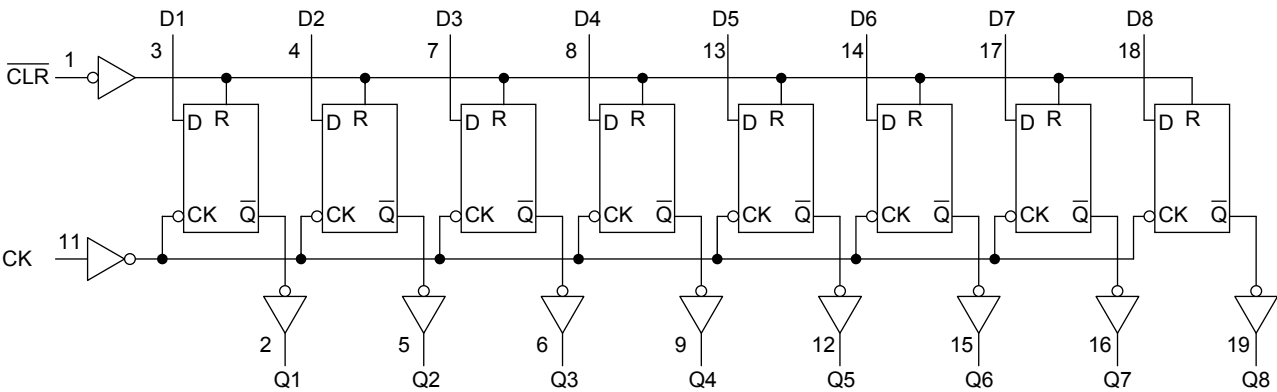


Truth Table

Inputs			Outputs	Function
CLR	D	CK	Q	
L	X	X	L	Clear
H	L		L	—
H	H		H	—
H	X		Q _n	No change

X: Don't care

System Diagram



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5~7.0	V
DC input voltage	V_{IN}	-0.5~7.0	V
DC output voltage	V_{OUT}	-0.5~ $V_{CC} + 0.5$	V
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC} /ground current	I_{CC}	±75	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	-65~150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0~5.5	V
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~ V_{CC}	V
Operating temperature	T_{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~100 ($V_{CC} = 3.3 \pm 0.3$ V)	ns/V
		0~20 ($V_{CC} = 5 \pm 0.5$ V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either V_{CC} or GND.

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
					VCC (V)	Min	Typ.	Max	Min		Max
Input voltage	“H” level	VIH	—	2.0	1.50	—	—	1.50	—	V	
				3.0~5.5	VCC × 0.7	—	—	VCC × 0.7	—		
	“L” level	VIL	—	2.0	—	—	0.50	—	0.50		
				3.0~5.5	—	—	VCC × 0.3	—	VCC × 0.3		
Output voltage	“H” level	VOH	VIN = VIH or VIL	IOH = -50 μA	2.0	1.9	2.0	—	1.9	—	V
					3.0	2.9	3.0	—	2.9	—	
					4.5	4.4	4.5	—	4.4	—	
				IOH = -4 mA	3.0	2.58	—	—	2.48	—	
					IOH = -8 mA	4.5	3.94	—	—	3.80	
	“L” level	VOL	VIN = VIH or VIL	IOL = 50 μA	2.0	—	0	0.1	—	0.1	
					3.0	—	0	0.1	—	0.1	
					4.5	—	0	0.1	—	0.1	
				IOL = 4 mA	3.0	—	—	0.36	—	0.44	
					IOL = 8 mA	4.5	—	—	0.36	—	
Input leakage current		IIN	VIN = 5.5 V or GND	0~5.5	—	—	±0.1	—	±1.0	μA	
Quiescent supply current		ICC	VIN = VCC or GND	5.5	—	—	4.0	—	40.0	μA	

Timing Requirements (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C		Ta = -40~85°C		Unit
			V _{CC} (V)	Typ.	Limit	Limit	
Minimum pulse width (CK)	t_w (L) t_w (H)	—	3.3 ± 0.3	—	5.5	6.5	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum pulse width ($\overline{\text{CLR}}$)	t_w (L)	—	3.3 ± 0.3	—	5.0	6.0	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum set-up time	t_s	—	3.3 ± 0.3	—	5.5	6.5	ns
			5.0 ± 0.5	—	4.5	4.5	
Minimum hold time	t_h	—	3.3 ± 0.3	—	1.0	1.0	ns
			5.0 ± 0.5	—	1.0	1.0	
Minimum removal time ($\overline{\text{CLR}}$)	t_{rem}	—	3.3 ± 0.3	—	2.5	2.5	ns
			5.0 ± 0.5	—	2.0	2.0	

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Typ.	Max	
Propagation delay time (CK-Q)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	8.7	13.6	ns
				50	—	11.2	17.1	
			5.0 ± 0.5	15	—	5.8	9.0	
				50	—	7.3	11.0	
Propagation delay time ($\overline{\text{CLR}}$ -Q)	t_{pHL}	—	3.3 ± 0.3	15	—	8.9	13.6	ns
				50	—	11.4	17.1	
			5.0 ± 0.5	15	—	5.2	8.5	
				50	—	6.7	10.5	
Maximum clock frequency	f_{max}	—	3.3 ± 0.3	15	75	120	—	MHz
				50	50	75	—	
			5.0 ± 0.5	15	120	165	—	
				50	80	110	—	
Output to output skew	t_{osLH} t_{osHL}	(Note 1)	3.3 ± 0.3	50	—	—	1.5	ns
			5.0 ± 0.5	50	—	—	1.0	
Input capacitance	C _{IN}	—	—	—	—	4	10	pF
Power dissipation capacitance	C _{PD}	(Note 2)	—	—	—	31	—	pF

Note 1: This parameter is guaranteed by design.

$$t_{\text{osLH}} = |t_{\text{pLHm}} - t_{\text{pLHn}}|, t_{\text{osHL}} = |t_{\text{pHLm}} - t_{\text{pHLn}}|$$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{\text{CC (opr)}} = C_{\text{PD}} \cdot V_{\text{CC}} \cdot f_{\text{IN}} + I_{\text{CC}}/8 \text{ (per F/F)}$$

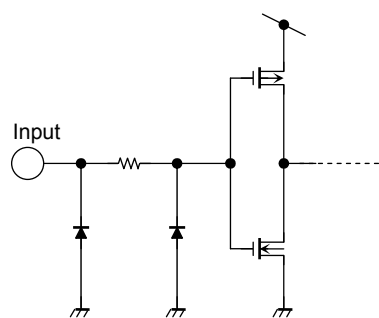
And the total C_{PD} when n pcs of flip-flop operate can be gained by the following equation:

$$C_{\text{PD (total)}} = 22 + 9 \cdot n$$

Noise Characteristics (Input: $t_r = t_f = 3\text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V _{CC} (V)	Typ.	Limit	
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.5	-0.8	V
Minimum high level dynamic input voltage V _{IH}	V _{IHD}	C _L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage V _{IL}	V _{ILD}	C _L = 50 pF	5.0	—	1.5	V

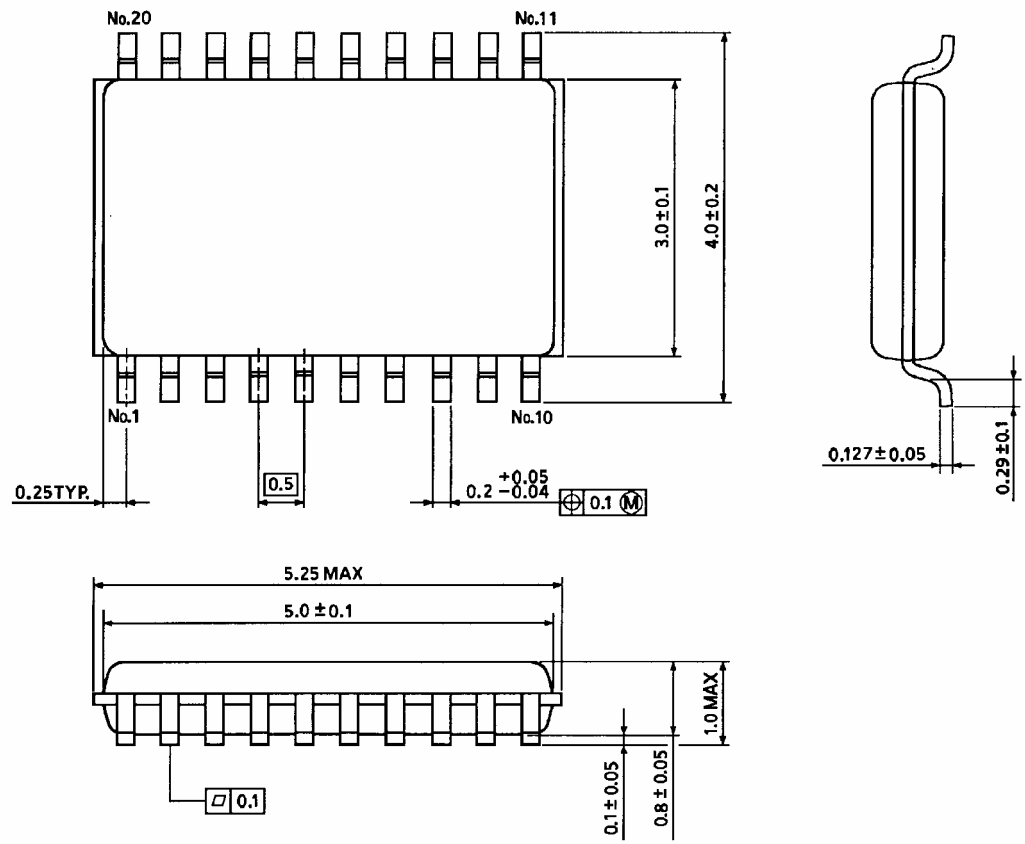
Input Equivalent Circuit



Package Dimensions

VSSOP20-P-0030-0.50

Unit : mm



Weight: 0.03 g (typ.)

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patents or other rights of TOSHIBA or the third parties.
- Please contact your sales representative for product-by-product details in this document regarding RoHS compatibility. Please use these products in this document in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses occurring as a result of noncompliance with applicable laws and regulations.